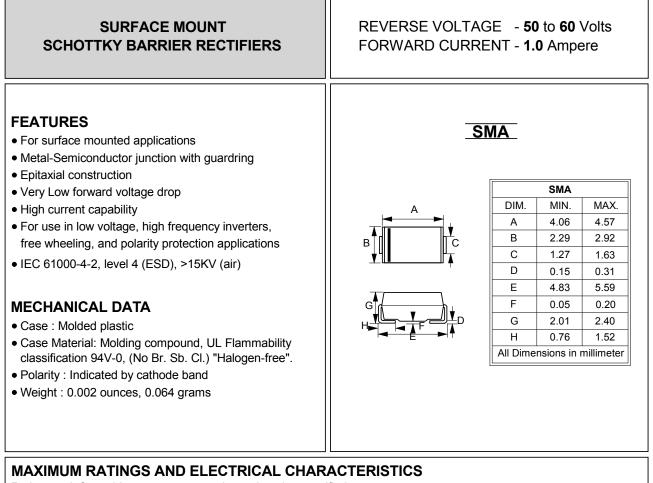
LITE ON SEMICONDUCTOR

B150 thru B160

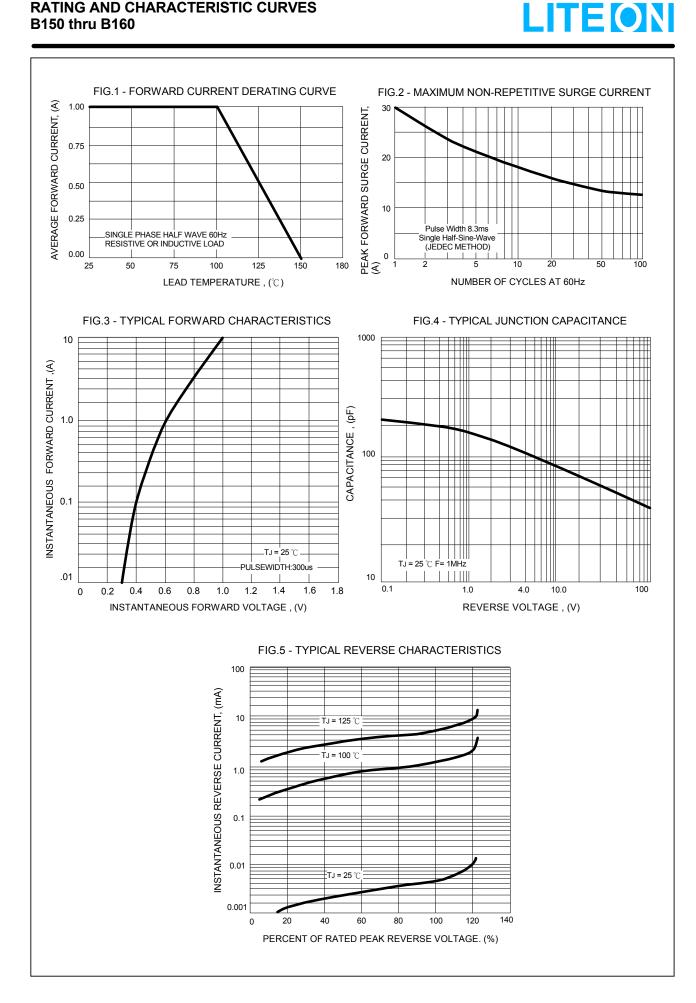


Ratings at 25° C ambient temperature unless otherwise specified.

	1			
CHARACTERISTICS	SYMBOL	B150	B160	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	60	V
Maximum RMS Voltage	VRMS	35	42	V
Maximum DC Blocking Voltage	VDC	50	60	V
Maximum Average Forward Rectified Current @TL =100 °C	l(AV)	1.0		A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC METHOD)	IFSM	30		A
Maximum forward Voltage at 1.0A DC	VF	0	0.7	
Maximum DC Reverse Current at Rated DC Blocking Voltage $@TJ = 25 \degree C$ $@TJ = 100 \degree C$	lr		0.05 10	
Typical Junction Capacitance (Note 1)	CJ	1.	110	
Typical Thermal Resistance (Note 2)	Røjl	2	20	
Operating Temperature Range	TJ	-55 to	-55 to +150	
Storage Temperature Range	Тѕтс	-55 to	+150	°C

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC. 2.Thermal Resistance Junction to Lead. REV. 10, Aug-2014, KSHA01

RATING AND CHARACTERISTIC CURVES B150 thru B160





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